PI74AVC+16260

12-Bit To 24-Bit Multiplexed D-Type Latch with 3-State Outputs

Product Features

- PI74AVC+16260 is designed for low voltage operation, V_{CC} = 1.65V to 3.6V
- True ±24mA Balanced Drive @ 3.3V
- I_{OFF} supports partial power-down operation
- 3.6V I/O Tolerant Inputs and Outputs
- All outputs contain noise reduction circuitry reducing noise without speed degradation
- Industrial operation at –40°C to +85°C
- Packages available:
  – 56-pin 240 mil wide plastic TSSOP (A)
  – 56-pin 173 mil wide plastic TSSOP (K)

Product Description

Pericom Semiconductor's PI74AVC+ series of logic circuits are produced using the Company's advanced sub-micron CMOS technology, achieving industry leading speed.

The PI74AVC+16260 is a 12-bit to 24-bit multiplexed D-type latch designed for 1.65V to 3.6 V_{CC} operation. It is used in applications where two separate datapaths must be multiplexed onto, or demultiplexed from, a single data path.

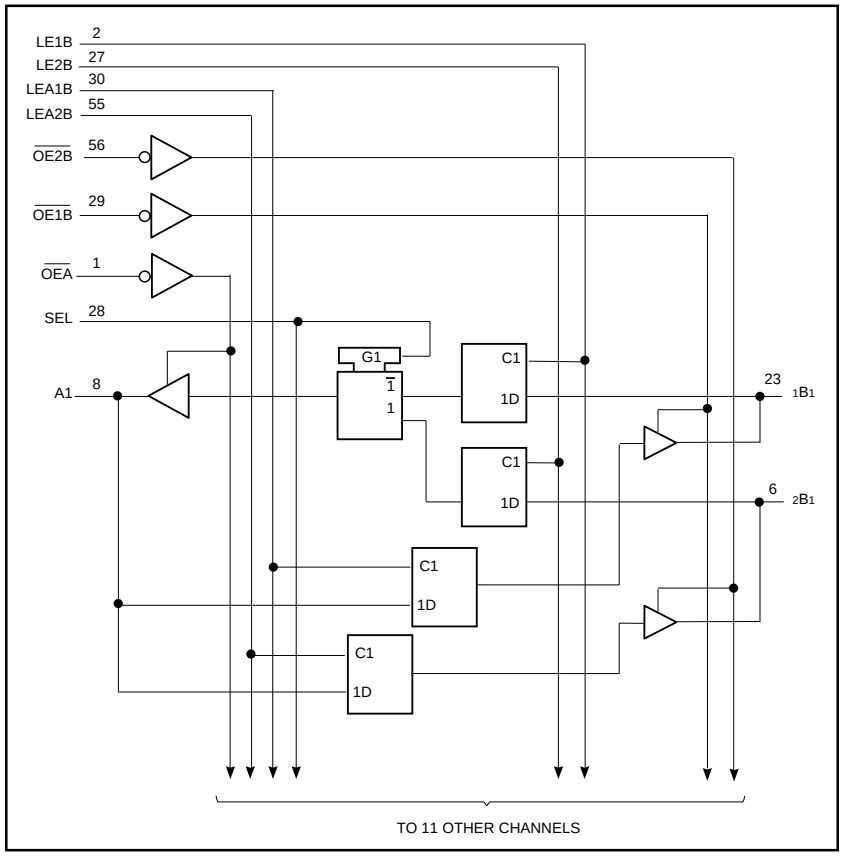
Typical applications include multiplexing and/or demultiplexing address and data information in microprocessor or bus-interface applications. This device is also useful in memory-interleaving applications.

Three 12-bit I/O ports (A1-A12, 1B1-1B12, and 2B1-2B12) are available for address and/or data transfer. The output-enable ($\overline{OE1B}$, $\overline{OE2B}$, and $\overline{OEA}$) inputs control the bus transceiver functions. The $\overline{OE1B}$ and $\overline{OE2B}$ control signals also allow bank control in the A-to-B direction.

Address and/or data information can be stored using the internal storage latches. The latch-enable (LE1B, LE2B, LEA1B, and LEA2B) inputs are used to control data storage. When the latch-enable input is HIGH, the latch is transparent. When the latch-enable input goes LOW, the data present at the inputs is latched and remains latched until the latch-enable input is returned HIGH.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor, the minimum value of the resistor is determined by the current-sinking capability of the driver.

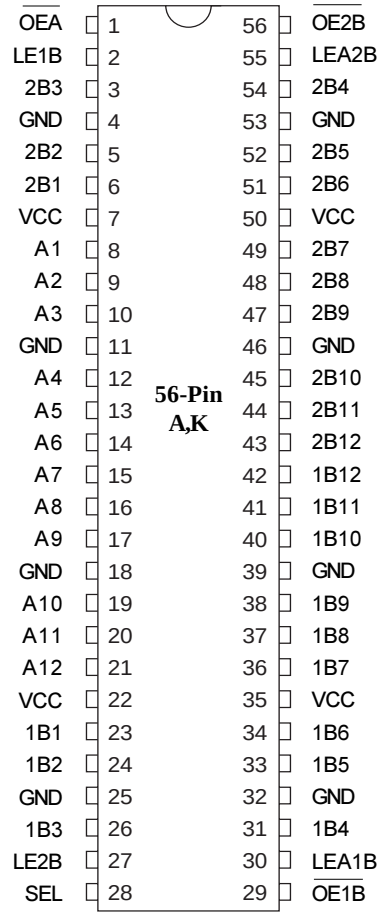
Logic Block Diagram



Product Pin Description

Pin Name	Description
$\overline{OE}$	Output Enable Input (Active LOW)
SEL	Select
LE	Latch Enable
A,1B,2B	Data Inputs
A,1B,2B	3-State Outputs
GND	Ground
V_{CC}	Power

Product Pin Configuration



Truth Tables(1)

B to A ($\overline{OEB}$ = H)

Inputs						Output A
1B	2B	SEL	LE1B	LE2B	$\overline{OEA}$	
H	X	H	H	X	L	H
L	X	H	H	X	L	L
X	X	H	L	X	L	A_0
X	H	L	X	H	L	H
X	L	L	X	H	L	L
X	X	L	X	L	L	A_0
X	X	X	X	X	H	Z

A to B ($\overline{OEA}$ = H)

INPUTS					OUTPUTS	
A	LEA1B	LEA2B	$\overline{OE1B}$	$\overline{OE2B}$	1B	2B
H	H	H	L	L	H	H
L	H	H	L	L	L	L
H	H	L	L	L	H	2B0
L	H	L	L	L	L	2B0
H	L	H	L	L	1B0	H
L	L	H	L	L	1B0	L
X	L	L	L	L	1B0	2B0
X	X	X	H	H	Z	Z
X	X	X	L	H	Active	Z
X	X	X	H	L	Z	Active
X	X	X	L	L	Active	Active

Note:

1. H = High Signal Level
   L = Low Signal Level
   X = Irrelevant
   Z = High Impedance

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Supply voltage range, V_{CC}	–0.5V to +4.6V
Input voltage range, V_I	–0.5V to +4.6V
Voltage range applied to any output in the high-impedance or power-off state, V_O(1)	–0.5V to +4.6V
Voltage range applied to any output in the high or low state, V_O(1,2)	–0.5V to V_{CC} +0.5V
Input clamp current, I_{IK} (V_I <0)	–50mA
Output clamp current, I_{OK} (V_O <0)	–50mA
Continuous output current, I_O	±50mA
Continuous current through each V_{CC} or GND	±100mA
Package thermal impedance, θ_{JA}(3): package A	64°C/W
package K	48°C/W
Storage Temperature range, T_{stg}	–65°C to 150°C

Note:
Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Notes:
1. Input & output negative-voltage ratings may be exceeded if the input and output curent rating are observed.
2. Output positive-voltage rating may be exceeded up to 4.6V maximum if theoutput current rating is observed.
3. The package thermal impedance is calculated in accordance with JESD 51.

Recommended Operating Conditions(1)

		Min.	Max.	Units
V_{CC} Supply Voltage	Operating	1.65	3.6	V
	Data retention only	1.2		
V_{IH} High-level Input Voltage	V_{CC} = 1.2V	V_{CC}		
	V_{CC} = 1.65V to 1.95V	0.65 x V_{CC}		
	V_{CC} = 2.3V to 2.7V	1.7		
	V_{CC} = 3V to 3.6V	2		
V_{IL} Low-level Input Voltage	V_{CC} = 1.2V		Gnd	
	V_{CC} = 1.65V to 1.95V		0.35 x V_{CC}	
	V_{CC} = 2.3V to 2.7V		0.7	
	V_{CC} = 3V to 3.6V		0.8	
V_I Input Voltage		0	3.6	
V_O Output Voltage	Active State	0	V_{CC}	
	3-State	0	3.6	
I_{OH} High-level output current	V_{CC} = 1.65V to 1.95V		– 6	mA
	V_{CC} = 2.3V to 2.7V		– 12	
	V_{CC} = 3V to 3.6V		– 24	
I_{OL} Low-level output current	V_{CC} = 1.65V to 1.95V		6	
	V_{CC} = 2.3V to 2.7V		12	
	V_{CC} = 3V to 3.6V		24	
$\Delta t/\Delta v$ Input transition rise or fall rate	V_{CC} = 1.65V to 3.6V		5	ns/V
T_A Operating free-air temperature		–40	85	°C

Notes:
1. All unused inputs must be held at V_{CC} or GND to ensure proper device operation.

DC Electrical Characteristics (Over the Operating Range, T_A = –40°C +85°C)

Parameters		Test Conditions[1]	V_{CC}	Min.	Max.	Units
V_{OH}		I_{OH} = –100µA	1.65V to 3.6V	V_{CC} –0.2V		V
		I_{OH} = –6mA V_{IH} = 1.07V	1.65V	1.2		
		I_{OH} = –12mA V_{IH} = 1.7V	2.3V	1.75		
		I_{OH} = –24mA V_{IH} = 2V	3V	2.0		
V_{OL}		I_{OL} = 100µA	1.65V to 3.6V		0.2	
		I_{OL} = 6mA V_{IH} = 0.57V	1.65V		0.45	
		I_{OL} = 12mA V_{IH} = 0.7V	2.3V		0.55	
		I_{OL} = 24mA V_{IH} = 0.8V	3V		0.75	
I_I	Control Inputs	V_I = V_{CC} or GND	3.6V		±2.5	µA
I_{OFF}		V_I or V_O = 3.6V	0		±10	
I_{OZ}		V_I = V_{CC} or GND	3.6V		±10	
I_{CC}		V_O = V_{CC} or GND I_O = 0	3.6V		40	
C_I	Control Inputs	V_I = V_{CC} or GND	2.5V		4	pF
			3.3V		4	
	Data Inputs		2.5V		6	
			3.3V		6	
C_O	Outputs	V_O = V_{CC} or GND	2.5V		8	
			3.3V		8	

Note: Typical values are measured at T_A = 25°C.

Timing Requirements over recommended operating free-air temperature range

(unless otherwise noted, see Figures 1 thru 4)

		V_{CC} = 1.2V		V_{CC} = 1.5V ± 0.1V		V_{CC} = 1.8V ± 0.15V		V_{CC} = 2.5V ± 0.2V		V_{CC} = 3.3V ± 0.3V		Units
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t_w	Pulse duration, LE1B, LE2B, LEA1B, or LEA2B High							3.0		3.0		ns
t_{su}	Setup time, data before LE1B, LE2B, LEA1B, or LEA2B							1.1		0.8		
t_h	Hold time, data after LE1B, LE2B, LEA1B, or LEA2B							1.5		1.0		

Switching Requirements over recommended operating free-air temperature range

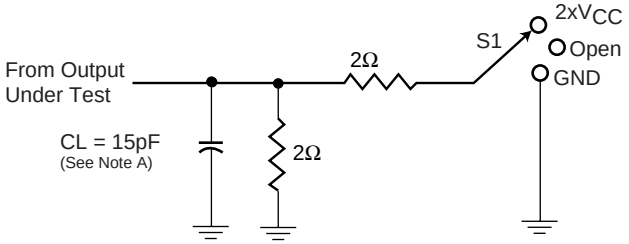
(unless otherwise noted, see Figures 1 thru 4)

Parameter	From (Input)	To (Output)	V_{CC} = 1.2V		V_{CC} = 1.5V ± 0.1V		V_{CC} = 1.8V ± 0.15V		V_{CC} = 2.5V ± 0.2V		V_{CC} = 3.3V ± 0.3V		Units
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t_{pd}	A or B	B or A								4.3		3.0	ns
	LE	A or B								4.4		3.1	
	$\overline{SEL}$	A								5.6		4.2	
t_{en}	$\overline{OE}$	A or B								5.4		4.0	
t_{dis}	$\overline{OE}$	A or B								4.6		3.5	

Operating Characteristics, T_A = 25°C

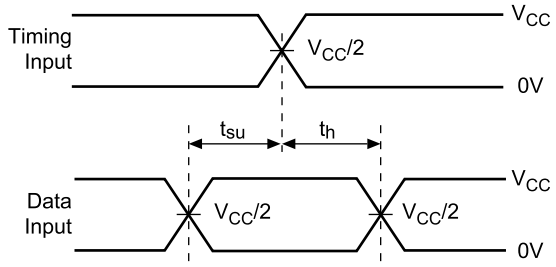
Parameter		Test Conditions	V_{CC} = 2.5V ±0.2V	V_{CC} = 3.3V ±0.3V	Units
			Typical		
C_{pd} Power Dissipation Capacitance	Outputs Enabled	C_L = 0pF, f = 10 MHz	TBD	TBD	pF
	Outputs Disabled		TBD	TBD	

PARAMETER MEASUREMENT INFORMATION
V_{CC} = 1.2V AND 1.5V ± 0.1V

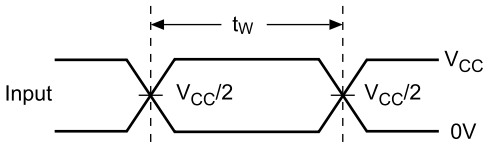


Load Circuit

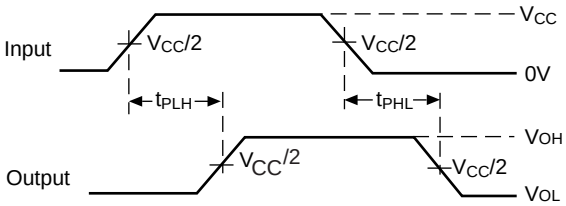
Test	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	2 x V_{CC}
t_{PHZ}/t_{PZH}	GND



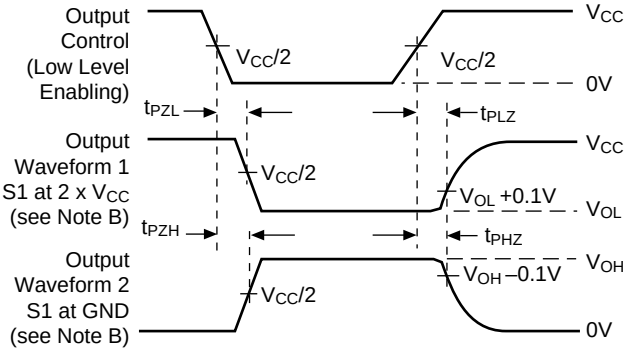
Voltage Waveforms
Setup and Hold Times



Voltage Waveforms
Pulse Duration



Voltage Waveforms
Propagation Delay Times



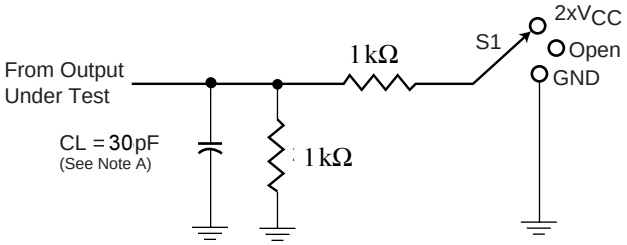
Voltage Waveforms
Enable and Disable Times

Figure 1. Load Circuit and Voltage Waveforms

Notes:

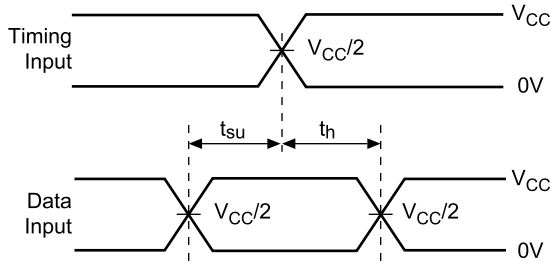
A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input impulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50Ω, t_R ≤ 2.0ns, t_F ≤ 2.0ns.
D. The outputs are measured one at a time with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}
F. t_{PZL} and t_{PZH} are the same as t_{en}
G. t_{PLH} and t_{PHL} are the same as t_{pd}

PARAMETER MEASUREMENT INFORMATION
V_{CC} = 1.8V ±0.15V

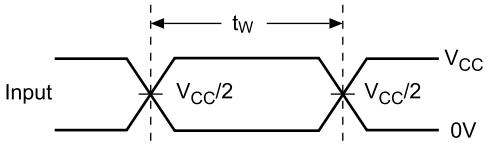


Load Circuit

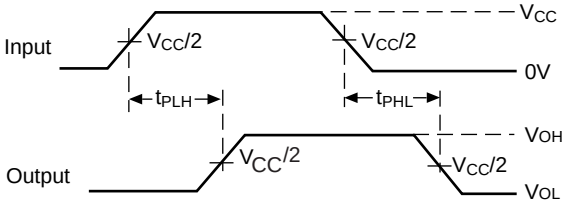
Test	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	2 x V_{CC}
t_{PHZ}/t_{PZH}	GND



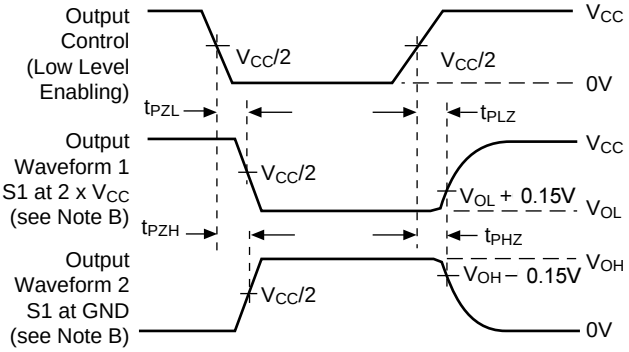
Voltage Waveforms
Setup and Hold Times



Voltage Waveforms
Pulse Duration



Voltage Waveforms
Propagation Delay Times



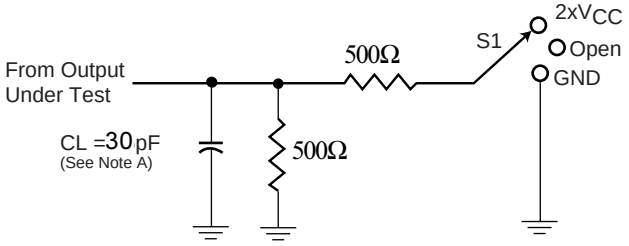
Voltage Waveforms
Enable and Disable Times

Figure 2. Load Circuit and Voltage Waveforms

Notes:

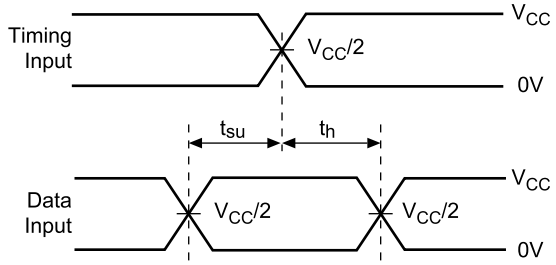
A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input impulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50Ω, t_R ≤ 2.0ns, t_F ≤ 2.0ns.
D. The outputs are measured one at a time with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}
F. t_{PZL} and t_{PZH} are the same as t_{en}
G. t_{PLH} and t_{PHL} are the same as t_{pd}

PARAMETER MEASUREMENT INFORMATION
V_{CC} = 2.5V ± 0.2V

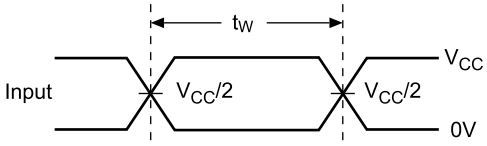


Test	S1
t_{pd} t_{PLZ}/t_{PZL} t_{PHZ}/t_{PZH}	Open 2 x V_{CC} GND

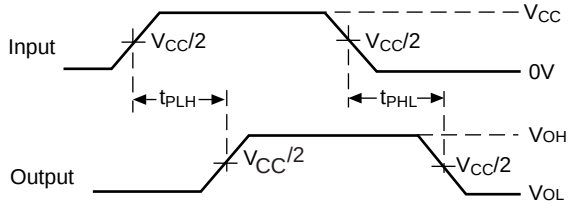
Load Circuit



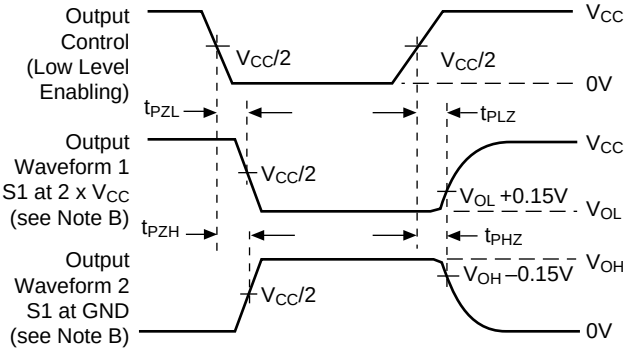
Voltage Waveforms
Setup and Hold Times



Voltage Waveforms
Pulse Duration



Voltage Waveforms
Propagation Delay Times



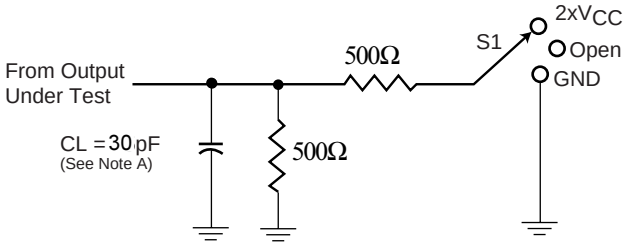
Voltage Waveforms
Enable and Disable Times

Figure 3. Load Circuit and Voltage Waveforms

Notes:

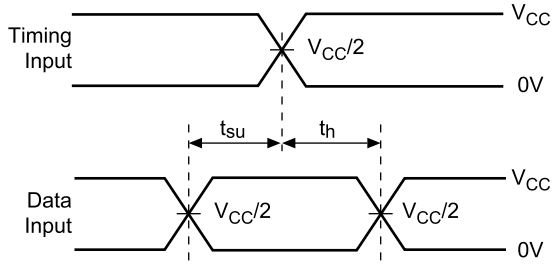
A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input impulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50Ω, t_R ≤ 2.0ns, t_F ≤ 2.0ns.
D. The outputs are measured one at a time with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}
F. t_{PZL} and t_{PZH} are the same as t_{en}
G. t_{PLH} and t_{PHL} are the same as t_{pd}

PARAMETER MEASUREMENT INFORMATION
V_{CC} = 3.3V ± 0.3V

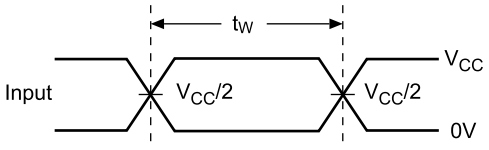


Test	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	2 x V_{CC}
t_{PHZ}/t_{PZH}	GND

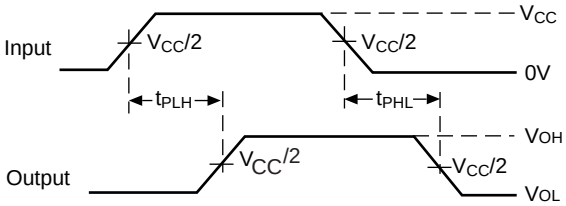
Load Circuit



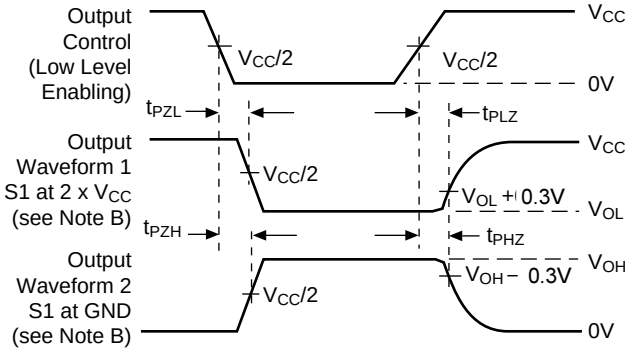
Voltage Waveforms
Setup and Hold Times



Voltage Waveforms
Pulse Duration



Voltage Waveforms
Propagation Delay Times



Voltage Waveforms
Enable and Disable Times

Figure 4. Load Circuit and Voltage Waveforms

Notes:

A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input impulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50Ω, t_R ≤ 2.0ns, t_F ≤ 2.0ns.
D. The outputs are measured one at a time with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}
F. t_{PZL} and t_{PZH} are the same as t_{en}
G. t_{PLH} and t_{PHL} are the same as t_{pd}